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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Obsolete
Core Processor	RL78
Core Size	16-Bit
Speed	24MHz
Connectivity	CSI, I <sup>2</sup> C, UART/USART
Peripherals	LVD, POR, PWM, WDT
Number of I/O	14
Program Memory Size	8KB (8K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	768 x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 5.5V
Data Converters	A/D 11x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	20-LSSOP (0.173", 4.40mm Width)
Supplier Device Package	20-LSSOP
Purchase URL	<a href="https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f10368asp-x0">https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f10368asp-x0</a>

### 1.3 Differences between the R5F102 Products and the R5F103 Products

The following are differences between the R5F102 products and the R5F103 products.

- Whether the data flash memory is mounted or not
- High-speed on-chip oscillator oscillation frequency accuracy
- Number of channels in serial interface
- Whether the DMA function is mounted or not
- Whether a part of the safety functions are mounted or not

#### 1.3.1 Data Flash

The data flash memory of 2 KB is mounted on the R5F102 products, but not on the R5F103 products.

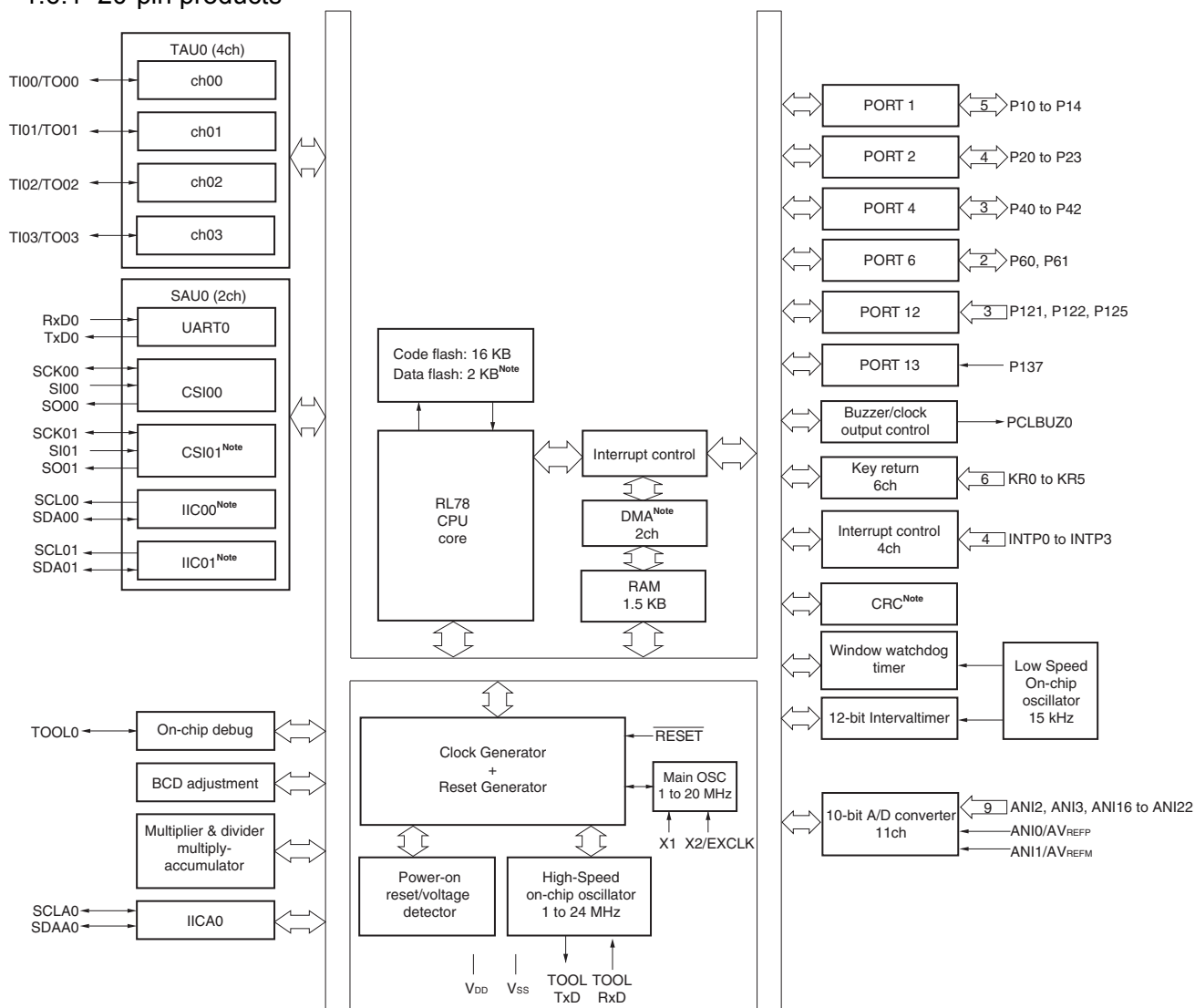
Product	Data Flash
<b>R5F102 products</b> R5F1026A, R5F1027A, R5F102AA, R5F10269, R5F10279, R5F102A9, R5F10268, R5F10278, R5F102A8, R5F10267, R5F10277, R5F102A7, R5F10266 <small>Note</small>	2KB
<b>R5F103 products</b> R5F1036A, R5F1037A, R5F103AA, R5F10369, R5F10379, R5F103A9, R5F10368, R5F10378 R5F103A8, R5F10367, R5F10377, R5F103A7, R5F10366	Not mounted

**Note** The RAM in the R5F10266 has capacity as small as 256 bytes. Depending on the customer's program specification, the stack area to execute the data flash library may not be kept and data may not be written to or erased from the data flash memory.

**Caution** When the flash memory is rewritten via a user program, the code flash area and RAM area are used because each library is used. When using the library, refer to RL78 Family Flash Self Programming Library Type01 User's Manual and RL78 Family Data Flash Library Type04 User's Manual.

## 1.6 Block Diagram

## 1.6.1 20-pin products



**Note** Provided only in the R5F102 products.

## 1.7 Outline of Functions

This outline describes the function at the time when Peripheral I/O redirection register (PIOR) is set to 00H.

(1/2)

&lt;R&gt;

Item		20-pin		24-pin		30-pin	
		R5F1026x	R5F1036x	R5F1027x	R5F1037x	R5F102Ax	R5F103Ax
Code flash memory		2 to 16 KB <sup>Note 1</sup>		4 to 16 KB			
Data flash memory		2 KB	–	2 KB	–	2 KB	–
RAM		256 B to 1.5 KB		512 B to 1.5 KB		512 B to 2KB	
Address space		1 MB					
Main system clock	High-speed system clock	X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) HS (High-speed main) mode : 1 to 20 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (High-speed main) mode : 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (Low-speed main) mode : 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V)					
	High-speed on-chip oscillator clock	HS (High-speed main) mode : 1 to 24 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (High-speed main) mode : 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (Low-speed main) mode : 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V)					
Low-speed on-chip oscillator clock		15 kHz (TYP)					
General-purpose register		(8-bit register × 8) × 4 banks					
Minimum instruction execution time		0.04167 μs (High-speed on-chip oscillator clock: f <sub>IH</sub> = 24 MHz operation)					
		0.05 μs (High-speed system clock: f <sub>MX</sub> = 20 MHz operation)					
Instruction set		• Data transfer (8/16 bits) • Adder and subtractor/logical operation (8/16 bits) • Multiplication (8 bits × 8 bits) • Rotate, barrel shift, and bit manipulation (set, reset, test, and Boolean operation), etc.					
I/O port	Total	18		22		26	
	CMOS I/O	12 (N-ch O.D. I/O [V <sub>DD</sub> withstand voltage]: 4)		16 (N-ch O.D. I/O [V <sub>DD</sub> withstand voltage]: 5)		21 (N-ch O.D. I/O [V <sub>DD</sub> withstand voltage]: 9)	
	CMOS input	4		4		3	
	N-ch open-drain I/O (6 V tolerance)	2					
Timer	16-bit timer	4 channels				8 channels	
	Watchdog timer	1 channel					
	12-bit Interval timer	1 channel					
	Timer output	4 channels (PWM outputs: 3 <sup>Note 3</sup> )				8 channels (PWM outputs: 7 <sup>Note 3</sup> <sup>Note 2</sup> )	

**Notes** 1. The self-programming function cannot be used in the R5F10266 and R5F10366.

2. The maximum number of channels when PIOR0 is set to 1.

3. The number of PWM outputs varies depending on the setting of channels in use (the number of masters and slaves). (See 6.9.3 Operation as multiple PWM output function.)

**Caution** When the flash memory is rewritten via a user program, the code flash area and RAM area are used because each library is used. When using the library, refer to RL78 Family Flash Self Programming Library Type01 User's Manual and RL78 Family Data Flash Library Type04 User's Manual.

## <R> 2. ELECTRICAL SPECIFICATIONS ( $T_A = -40$ to $+85^\circ\text{C}$ )

<R> This chapter describes the following electrical specifications.

Target products A: Consumer applications  $T_A = -40$  to  $+85^\circ\text{C}$

<R> R5F102xxAxx, R5F103xxAxx

D: Industrial applications  $T_A = -40$  to  $+85^\circ\text{C}$

<R> R5F102xxDxx, R5F103xxDxx

G: Industrial applications when  $T_A = -40$  to  $+105^\circ\text{C}$  products is used in the range of  $T_A = -40$  to  $+85^\circ\text{C}$

<R> R5F102xxGxx

**Cautions** 1. The RL78 microcontrollers have an on-chip debug function, which is provided for development and evaluation. Do not use the on-chip debug function in products designated for mass production, because the guaranteed number of rewritable times of the flash memory may be exceeded when this function is used, and product reliability therefore cannot be guaranteed. Renesas Electronics is not liable for problems occurring when the on-chip debug function is used.

2. The pins mounted depend on the product. Refer to 2.1 Port Functions to 2.2.1 Functions for each product.

## 2.3.2 Supply current characteristics

## (1) 20-, 24-pin products

 $(T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V})$ 

(1/2)

Parameter	Symbol	Conditions					MIN.	TYP.	MAX.	Unit
Supply current <sup>Note 1</sup>	I <sub>DD1</sub>	Operating mode	HS(High-speed main) mode <sup>Note 4</sup>	f <sub>IH</sub> = 24 MHz <sup>Note 3</sup>	Basic operation	V <sub>DD</sub> = 5.0 V		1.5		mA
						V <sub>DD</sub> = 3.0 V		1.5		
					Normal operation	V <sub>DD</sub> = 5.0 V		3.3	5.0	mA
						V <sub>DD</sub> = 3.0 V		3.3	5.0	
							V <sub>DD</sub> = 5.0 V		2.5	3.7
				V <sub>DD</sub> = 3.0 V			2.5	3.7		
				LS(Low-speed main) mode <sup>Note 4</sup>	f <sub>IH</sub> = 8 MHz <sup>Note 3</sup>	V <sub>DD</sub> = 3.0 V		1.2	1.8	mA
						V <sub>DD</sub> = 2.0 V		1.2	1.8	
				HS(High-speed main) mode <sup>Note 4</sup>	f <sub>MX</sub> = 20 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 5.0 V	Square wave input		2.8	4.4	mA
						Resonator connection		3.0	4.6	
			f <sub>MX</sub> = 20 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V			Square wave input		2.8	4.4	mA
						Resonator connection		3.0	4.6	
			f <sub>MX</sub> = 10 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 5.0 V		Square wave input		1.8	2.6	mA	
					Resonator connection		1.8	2.6		
			f <sub>MX</sub> = 10 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V		Square wave input		1.8	2.6	mA	
					Resonator connection		1.8	2.6		
			LS(Low-speed main) mode <sup>Note 4</sup>	f <sub>MX</sub> = 8 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		1.1	1.7	mA	
					Resonator connection		1.1	1.7		
				f <sub>MX</sub> = 8 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 2.0 V	Square wave input		1.1	1.7	mA	
					Resonator connection		1.1	1.7		

**Notes** 1. Total current flowing into  $V_{DD}$ , including the input leakage current flowing when the level of the input pin is fixed to  $V_{DD}$  or  $V_{SS}$ . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.

2. When high-speed on-chip oscillator clock is stopped.

3. When high-speed system clock is stopped

4. Relationship between operation voltage width, operation frequency of CPU and operation mode is as follows.

HS(High speed main) mode:  $V_{DD} = 2.7\text{ V}$  to  $5.5\text{ V}$  @  $1\text{ MHz}$  to  $24\text{ MHz}$

$V_{DD} = 2.4\text{ V}$  to  $5.5\text{ V}$  @  $1\text{ MHz}$  to  $16\text{ MHz}$

LS(Low speed main) mode:  $V_{DD} = 1.8\text{ V}$  to  $5.5\text{ V}$  @  $1\text{ MHz}$  to  $8\text{ MHz}$

**Remarks** 1.  $f_{MX}$ : High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

2.  $f_{IH}$ : high-speed on-chip oscillator clock frequency

3. Temperature condition of the TYP. value is  $T_A = 25^\circ\text{C}$ .

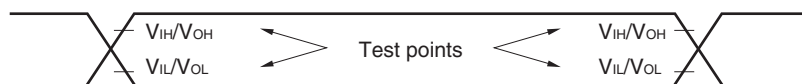
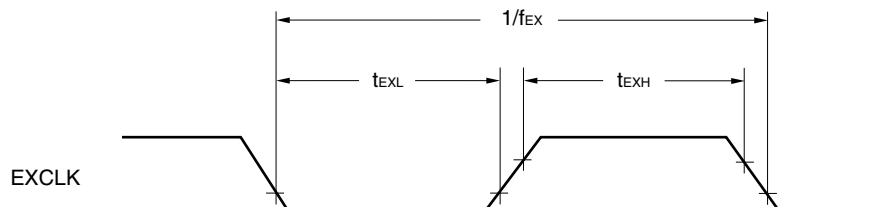
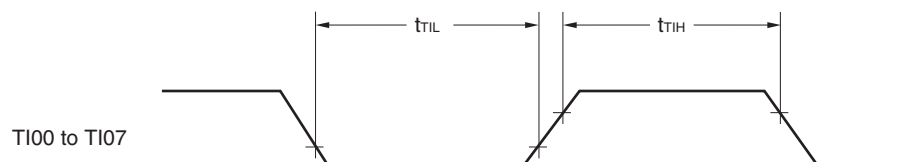
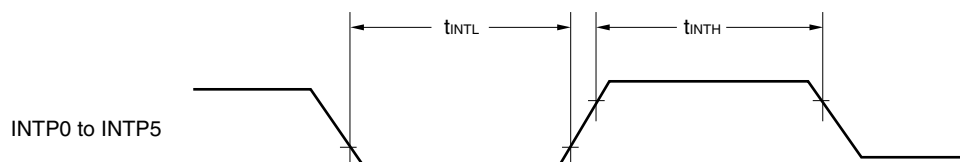
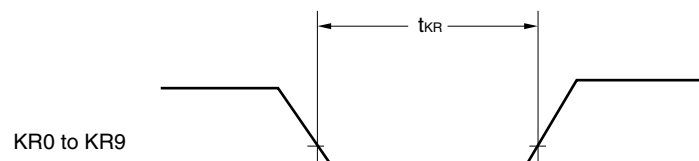
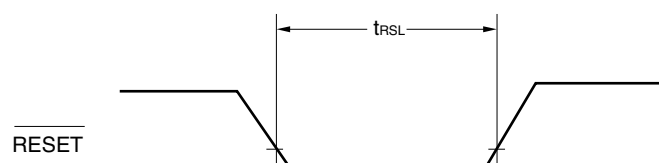
## 2.4 AC Characteristics

(TA = -40 to +85°C, 1.8 V ≤ VDD ≤ 5.5 V, VSS = 0 V)

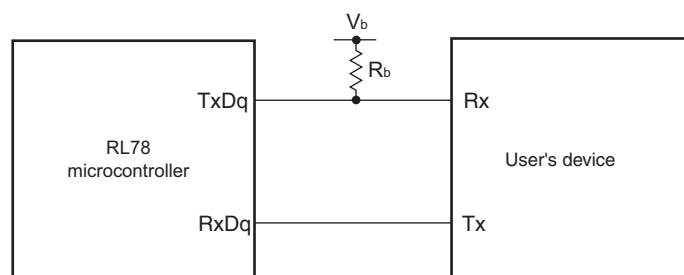
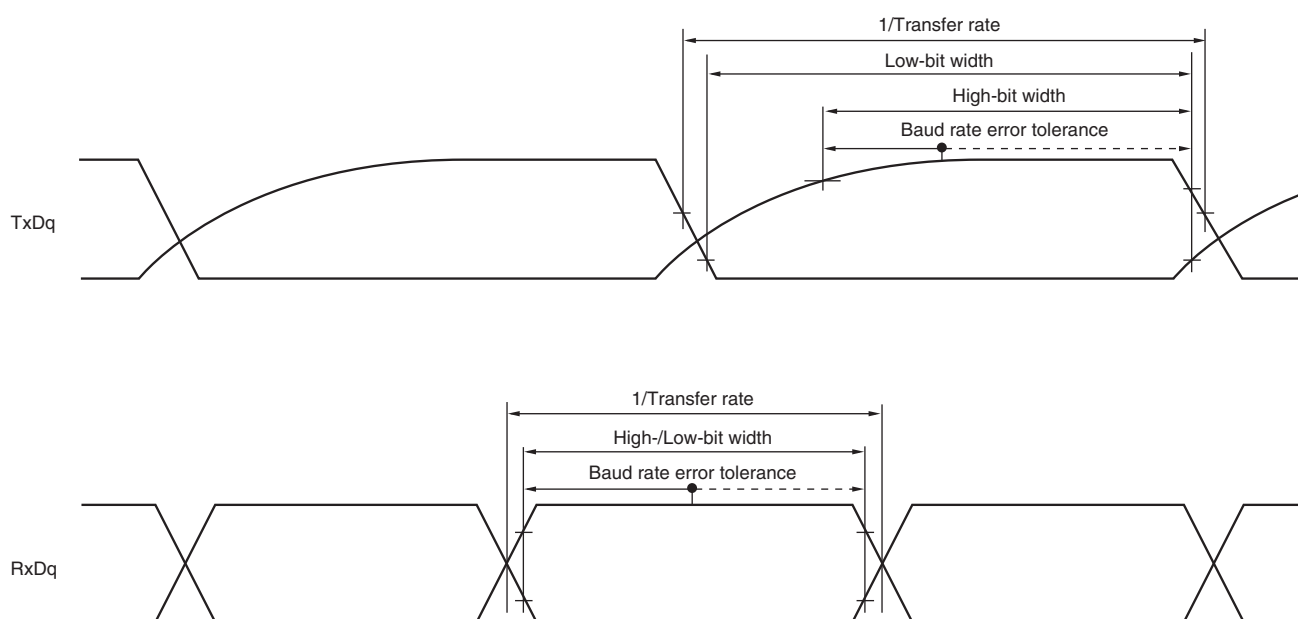
Items	Symbol	Conditions			MIN.	TYP.	MAX.	Unit
Instruction cycle (minimum instruction execution time)	TCY	Main system clock (fMAIN) operation	HS (High-speed main) mode	2.7 V ≤ VDD ≤ 5.5 V	0.04167		1	μs
				2.4 V ≤ VDD < 2.7 V	0.0625		1	μs
			LS (Low-speed main) mode	1.8 V ≤ VDD ≤ 5.5 V	0.125		1	μs
		During self programming	HS (High-speed main) mode	2.7 V ≤ VDD ≤ 5.5 V	0.04167		1	μs
				2.4 V ≤ VDD < 2.7 V	0.0625		1	μs
			LS (Low-speed main) mode	1.8 V ≤ VDD ≤ 5.5 V	0.125		1	μs
External main system clock frequency	fEX	2.7 V ≤ VDD ≤ 5.5 V			1.0		20.0	MHz
		2.4 V ≤ VDD < 2.7 V			1.0		16.0	MHz
		1.8 V ≤ VDD < 2.4 V			1.0		8.0	MHz
External main system clock input high-level width, low-level width	tEXH, tEXL	2.7 V ≤ VDD ≤ 5.5 V			24			ns
		2.4 V ≤ VDD < 2.7 V			30			ns
		1.8 V ≤ VDD < 2.4 V			60			ns
TI00 to TI07 input high-level width, low-level width	tTIH, tTIL				1/fMCK + 10			ns
TO00 to TO07 output frequency	fTO	4.0 V ≤ VDD ≤ 5.5 V					12	MHz
		2.7 V ≤ VDD < 4.0 V					8	MHz
		1.8 V ≤ VDD < 2.7 V					4	MHz
PCLBUZ0, or PCLBUZ1 output frequency	fPCL	4.0 V ≤ VDD ≤ 5.5 V					16	MHz
		2.7 V ≤ VDD < 4.0 V					8	MHz
		1.8 V ≤ VDD < 2.7 V					4	MHz
INTP0 to INTP5 input high-level width, low-level width	tINTH, tINTL				1			μs
KR0 to KR9 input available width	tKR				250			ns
RESET low-level width	tRSL				10			μs

**Remark** fMCK: Timer array unit operation clock frequency

(Operation clock to be set by the timer clock select register 0 (TPS0) and the CKS0n bit of timer mode register 0n (TMR0n). n: Channel number (n = 0 to 7))

**AC Timing Test Point****External Main System Clock Timing****TI/TO Timing****Interrupt Request Input Timing****Key Interrupt Input Timing****RESET Input Timing**



**UART mode connection diagram (during communication at different potential)****UART mode bit width (during communication at different potential) (reference)**

- Remarks**
1.  $R_b[\Omega]$ : Communication line (TxDq) pull-up resistance,  $C_b[\text{F}]$ : Communication line (TxDq) load capacitance,  $V_b[\text{V}]$ : Communication line voltage
  2. q: UART number ( $q = 0$  to  $2$ ), g: PIM and POM number ( $g = 0, 1$ )
  3.  $f_{\text{MCK}}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the serial clock select register m (SPSm) and the CKSmn bit of serial mode register mn (SMRmn).  
m: Unit number, n: Channel number ( $mn = 00$  to  $03, 10, 11$ ))
  4. UART0 of the 20- and 24-pin products supports communication at different potential only when the peripheral I/O redirection function is not used.

**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output) (3/3)****( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

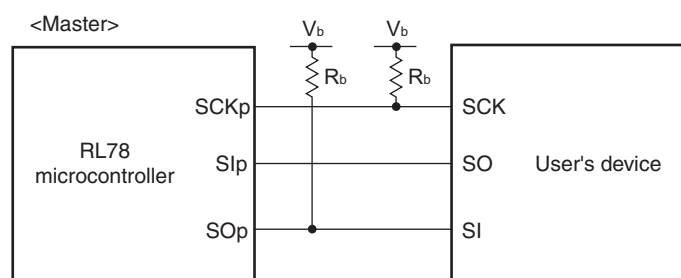
Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	
Slp setup time (to SCKp↓) <sup>Note 1</sup>	$t_{SIK1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	44		110		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	44		110		ns
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ <sup>Note 2</sup> , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	110		110		ns
Slp hold time (from SCKp↓) <sup>Note 1</sup>	$t_{KSI1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	19		19		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	19		19		ns
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ <sup>Note 2</sup> , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	19		19		ns
Delay time from SCKp↑ to SOp output <sup>Note 1</sup>	$t_{KSO1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$		25		25	ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$		25		25	ns
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ <sup>Note 2</sup> , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$		25		25	ns

**Notes** 1. When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.2. Use it with  $V_{DD} \geq V_b$ .**Cautions** 1. Select the TTL input buffer for the Slp pin and the N-ch open drain output ( $V_{DD}$  tolerance) mode for the SOp pin and SCKp pin by using port input mode register 1 (PIM1) and port output mode register 1 (POM1). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.

2. CSI01 and CSI11 cannot communicate at different potential.

**Remarks** 1.  $R_b$  [ $\Omega$ ]: Communication line (SCKp, SOp) pull-up resistance,  $C_b$  [F]: Communication line (SCKp, SOp) load capacitance,  $V_b$  [V]: Communication line voltage

2. p: CSI number (p = 00, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0)

**CSI mode connection diagram (during communication at different potential)**

**(10) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I<sup>2</sup>C mode)****( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	
SCLr clock frequency	$f_{SCL}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.8\text{ k}\Omega$		400 <sup>Note1</sup>		300 <sup>Note1</sup>	kHz
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$		400 <sup>Note1</sup>		300 <sup>Note1</sup>	kHz
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , <sup>Note2</sup> $C_b = 100\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$		300 <sup>Note1</sup>		300 <sup>Note1</sup>	kHz
Hold time when SCLr = "L"	$t_{LOW}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.8\text{ k}\Omega$	1150		1550		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	1150		1550		ns
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , <sup>Note2</sup> $C_b = 100\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	1550		1550		ns
Hold time when SCLr = "H"	$t_{HIGH}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.8\text{ k}\Omega$	675		610		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	600		610		ns
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , <sup>Note2</sup> $C_b = 100\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	610		610		ns
Data setup time (reception)	$t_{SU:DAT}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.8\text{ k}\Omega$	$1/f_{MCK}$ + 190 <sup>Note3</sup>		$1/f_{MCK}$ + 190 <sup>Note3</sup>		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	$1/f_{MCK}$ + 190 <sup>Note3</sup>		$1/f_{MCK}$ + 190 <sup>Note3</sup>		ns
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , <sup>Note2</sup> $C_b = 100\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	$1/f_{MCK}$ + 190 <sup>Note3</sup>		$1/f_{MCK}$ + 190 <sup>Note3</sup>		ns
Data hold time (transmission)	$t_{HD:DAT}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.8\text{ k}\Omega$	0	355	0	355	ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	0	355	0	355	ns
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , <sup>Note2</sup> $C_b = 100\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	0	405	0	405	ns

**Notes** 1. The value must also be equal to or less than  $f_{MCK}/4$ .2. Use it with  $V_{DD} \geq V_b$ .3. Set  $t_{SU:DAT}$  so that it will not exceed the hold time when SCLr = "L" or SCLr = "H".**Cautions** 1. Select the TTL input buffer and the N-ch open drain output ( $V_{DD}$  tolerance) mode for the SDAr pin and the N-ch open drain output ( $V_{DD}$  tolerance) mode for the SCLr pin by using port input mode register 1 (PIM1) and port output mode register 1 (POM1). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.

2. IIC01 and IIC11 cannot communicate at different potential.

(Remarks are listed on the next page.)

## 2.9 Dedicated Flash Memory Programmer Communication (UART)

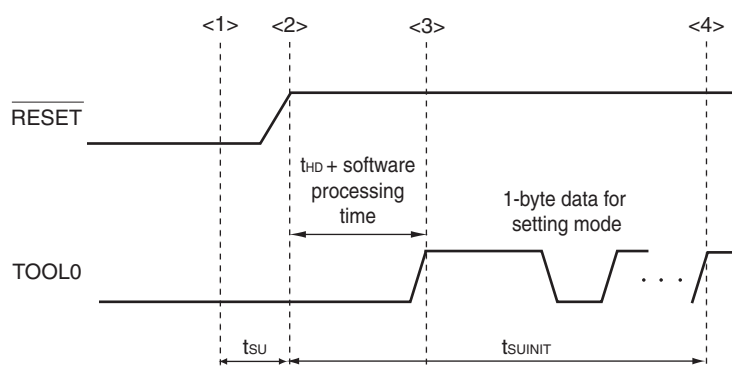
( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate		During serial programming	115,200		1,000,000	bps

## 2.10 Timing of Entry to Flash Memory Programming Modes

( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Time to complete the communication for the initial setting after the external reset is released	$t_{\text{SUNIT}}$	POR and LVD reset are released before external reset release			100	ms
Time to release the external reset after the TOOL0 pin is set to the low level	$t_{\text{SU}}$	POR and LVD reset are released before external reset release	10			$\mu\text{s}$
Time to hold the TOOL0 pin at the low level after the external reset is released (excluding the processing time of the firmware to control the flash memory)	$t_{\text{HD}}$	POR and LVD reset are released before external reset release	1			ms



- <1> The low level is input to the TOOL0 pin.
- <2> The external reset is released (POR and LVD reset must be released before the external reset is released.).
- <3> The TOOL0 pin is set to the high level.
- <4> Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

**Remark**  $t_{\text{SUNIT}}$ : Communication for the initial setting must be completed within 100 ms after the external reset is released during this period.

$t_{\text{SU}}$ : Time to release the external reset after the TOOL0 pin is set to the low level

$t_{\text{HD}}$ : Time to hold the TOOL0 pin at the low level after the external reset is released (excluding the processing time of the firmware to control the flash memory)

## 3.1 Absolute Maximum Ratings

Absolute Maximum Ratings (T<sub>A</sub> = 25°C)

Parameter	Symbols	Conditions		Ratings	Unit
Supply Voltage	V <sub>DD</sub>			-0.5 to +6.5	V
REGC terminal input voltage <sup>Note 1</sup>	V <sub>I REGC</sub>	REGC		-0.3 to +2.8 and -0.3 to V <sub>DD</sub> + 0.3 <sup>Note 2</sup>	V
Input Voltage	V <sub>I1</sub>	Other than P60, P61		-0.3 to V <sub>DD</sub> + 0.3 <sup>Note 3</sup>	V
	V <sub>I2</sub>	P60, P61 (N-ch open drain)		-0.3 to 6.5	V
Output Voltage	V <sub>O</sub>			-0.3 to V <sub>DD</sub> + 0.3 <sup>Note 3</sup>	V
Analog input voltage	V <sub>AI</sub>	20, 24-pin products: ANI0 to ANI3, ANI16 to ANI22 30-pin products: ANI0 to ANI3, ANI16 to ANI19		-0.3 to V <sub>DD</sub> + 0.3 and -0.3 to AVREF(+) + 0.3 <sup>Notes 3, 4</sup>	V
Output current, high	I <sub>OH1</sub>	Per pin	Other than P20 to P23	-40	mA
		Total of all pins	All the terminals other than P20 to P23	-170	mA
			20-, 24-pin products: P40 to P42 30-pin products: P00, P01, P40, P120	-70	mA
			20-, 24-pin products: P00 to P03 <sup>Note 5</sup> , P10 to P14 30-pin products: P10 to P17, P30, P31, P50, P51, P147	-100	mA
	I <sub>OH2</sub>	Per pin	P20 to P23	-0.5	mA
		Total of all pins		-2	mA
Output current, low	I <sub>OL1</sub>	Per pin	Other than P20 to P23	40	mA
		Total of all pins	All the terminals other than P20 to P23	170	mA
			20-, 24-pin products: P40 to P42 30-pin products: P00, P01, P40, P120	70	mA
			20-, 24-pin products: P00 to P03 <sup>Note 5</sup> , P10 to P14, P60, P61 30-pin products: P10 to P17, P30, P31, P50, P51, P60, P61, P147	100	mA
	I <sub>OL2</sub>	Per pin	P20 to P23	1	mA
		Total of all pins		5	mA
Operating ambient temperature	T <sub>A</sub>			-40 to +105	°C
Storage temperature	T <sub>stg</sub>			-65 to +150	°C

**Notes** 1. 30-pin product only.

2. Connect the REGC pin to V<sub>SS</sub> via a capacitor (0.47 to 1 μF). This value determines the absolute maximum rating of the REGC pin. Do not use it with voltage applied.

3. Must be 6.5 V or lower.

4. Do not exceed AVREF(+) + 0.3 V in case of A/D conversion target pin.

5. 24-pin products only.

**Caution** Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

**Remarks** 1. Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

2. AVREF(+) : + side reference voltage of the A/D converter.

3. V<sub>SS</sub> : Reference voltage

**( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )****(4/4)**

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Output voltage, low	V <sub>OL1</sub>	20-, 24-pin products: P00 to P03 <sup>Note</sup> , P10 to P14, P40 to P42 30-pin products: P00, P01, P10 to P17, P30, P31, P40, P50, P51, P120, P147	4.0 V $\leq V_{DD} \leq 5.5\text{ V}$ , I <sub>OL1</sub> = 8.5 mA			0.7	V
			2.7 V $\leq V_{DD} \leq 5.5\text{ V}$ , I <sub>OL1</sub> = 3.0 mA			0.6	V
			2.7 V $\leq V_{DD} \leq 5.5\text{ V}$ , I <sub>OL1</sub> = 1.5 mA			0.4	V
			2.4 V $\leq V_{DD} \leq 5.5\text{ V}$ , I <sub>OL1</sub> = 0.6 mA			0.4	V
	V <sub>OL2</sub>	P20 to P23	I <sub>OL2</sub> = 400 $\mu\text{A}$			0.4	V
	V <sub>OL3</sub>	P60, P61	4.0 V $\leq V_{DD} \leq 5.5\text{ V}$ , I <sub>OL1</sub> = 15.0 mA			2.0	V
			4.0 V $\leq V_{DD} \leq 5.5\text{ V}$ , I <sub>OL1</sub> = 5.0 mA			0.4	V
			2.7 V $\leq V_{DD} \leq 5.5\text{ V}$ , I <sub>OL1</sub> = 3.0 mA			0.4	V
			2.4 V $\leq V_{DD} \leq 5.5\text{ V}$ , I <sub>OL1</sub> = 2.0 mA			0.4	V
Input leakage current, high	I <sub>LIH1</sub>	Other than P121, P122	V <sub>I</sub> = V <sub>DD</sub>			1	$\mu\text{A}$
	I <sub>LIH2</sub>	P121, P122 (X1, X2/EXCLK)	V <sub>I</sub> = V <sub>DD</sub> Input port or external clock input			1	$\mu\text{A}$
			When resonator connected			10	$\mu\text{A}$
Input leakage current, low	I <sub>LIL1</sub>	Other than P121, P122	V <sub>I</sub> = V <sub>SS</sub>			-1	$\mu\text{A}$
	I <sub>LIL2</sub>	P121, P122 (X1, X2/EXCLK)	V <sub>I</sub> = V <sub>SS</sub> Input port or external clock input			-1	$\mu\text{A}$
			When resonator connected			-10	$\mu\text{A}$
On-chip pull-up resistance	R <sub>U</sub>	20-, 24-pin products: P00 to P03 <sup>Note</sup> , P10 to P14, P40 to P42, P125, RESET 30-pin products: P00, P01, P10 to P17, P30, P31, P40, P50, P51, P120, P147	V <sub>I</sub> = V <sub>SS</sub> , input port	10	20	100	k $\Omega$

**Note** 24-pin products only.**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

## (1) 20-, 24-pin products

 $(T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V})$ 

(2/2)

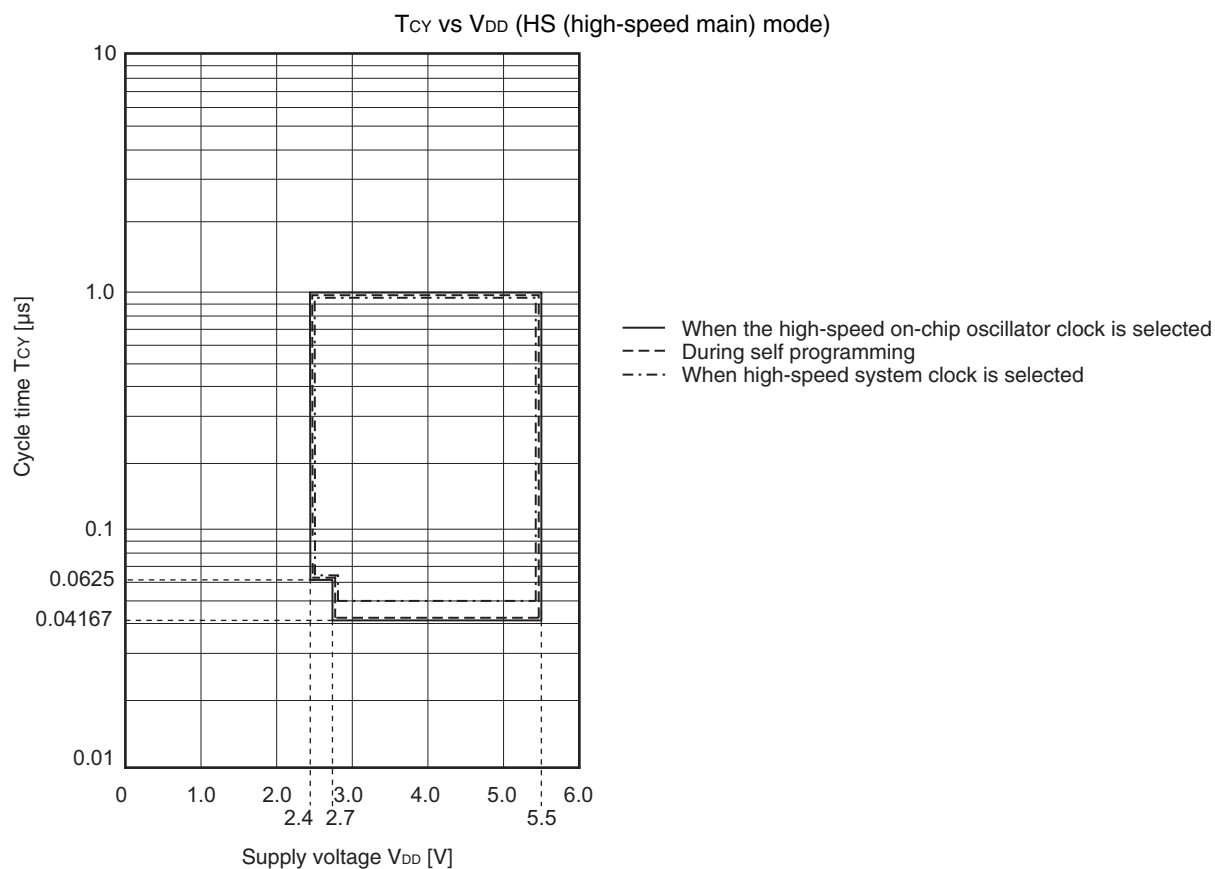
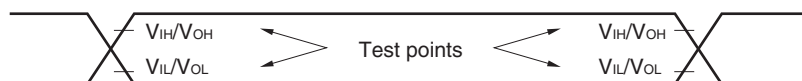
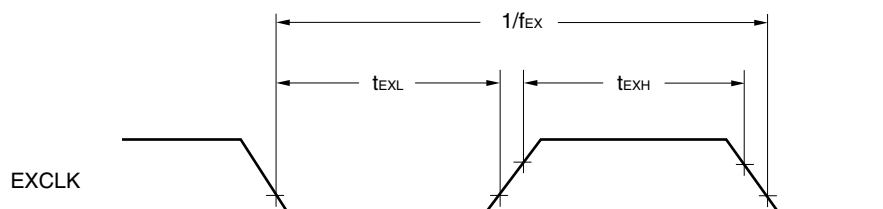
Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit
Supply current <sup>Note 1</sup>	I <sub>DD2</sub> <sup>Note 2</sup>	HALT mode	HS (High-speed main) mode <sup>Note 6</sup>	f <sub>IH</sub> = 24 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V		440	2230	μA
					V <sub>DD</sub> = 3.0 V		440	2230	
				f <sub>IH</sub> = 16 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V		400	1650	μA
					V <sub>DD</sub> = 3.0 V		400	1650	
				f <sub>MX</sub> = 20 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 5.0 V	Square wave input		280	1900	μA
					Resonator connection		450	2000	
				f <sub>MX</sub> = 20 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		280	1900	μA
					Resonator connection		450	2000	
				f <sub>MX</sub> = 10 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 5.0 V	Square wave input		190	1010	μA
					Resonator connection		260	1090	
				f <sub>MX</sub> = 10 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		190	1010	μA
					Resonator connection		260	1090	
	I <sub>DD3</sub> <sup>Note 5</sup>	STOP mode	T <sub>A</sub> = −40°C				0.19	0.50	μA
			T <sub>A</sub> = +25°C				0.24	0.50	
			T <sub>A</sub> = +50°C				0.32	0.80	
			T <sub>A</sub> = +70°C				0.48	1.20	
			T <sub>A</sub> = +85°C				0.74	2.20	
			T <sub>A</sub> = +105°C				1.50	10.20	

- Notes**
1. Total current flowing into  $V_{DD}$ , including the input leakage current flowing when the level of the input pin is fixed to  $V_{DD}$  or  $V_{SS}$ . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. During HALT instruction execution by flash memory.
  3. When high-speed on-chip oscillator clock is stopped.
  4. When high-speed system clock is stopped.
  5. Not including the current flowing into the 12-bit interval timer and watchdog timer.
  6. Relationship between operation voltage width, operation frequency of CPU and operation mode is as follows.

HS (High speed main) mode:  $V_{DD} = 2.7\text{ V}$  to  $5.5\text{ V}$  @  $1\text{ MHz}$  to  $24\text{ MHz}$

$V_{DD} = 2.4\text{ V}$  to  $5.5\text{ V}$  @  $1\text{ MHz}$  to  $16\text{ MHz}$

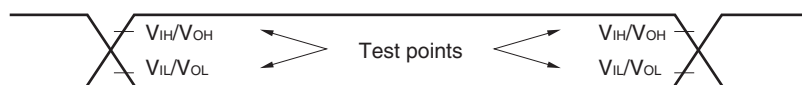
- Remarks**
1.  $f_{MX}$ : High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
  2.  $f_{IH}$ : high-speed on-chip oscillator clock frequency
  3. Except temperature condition of the TYP. value is  $T_A = 25^\circ\text{C}$ , other than STOP mode

**Minimum Instruction Execution Time during Main System Clock Operation****AC Timing Test Point****External Main System Clock Timing**



### 3.5 Peripheral Functions Characteristics

#### AC Timing Test Point



#### 3.5.1 Serial array unit

##### (1) During communication at same potential (UART mode)

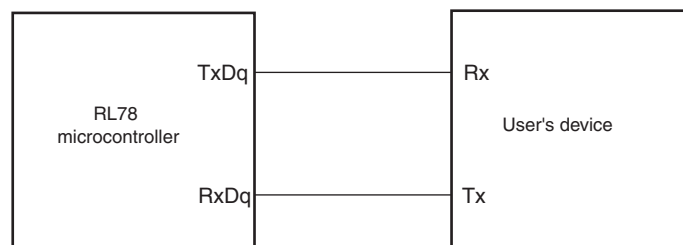
( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
Transfer rate <small>Note 1</small>		Theoretical value of the maximum transfer rate $f_{CLK} = f_{MCK}$ <small>Note2</small>		$f_{MCK}/12$	bps
				2.0	Mbps

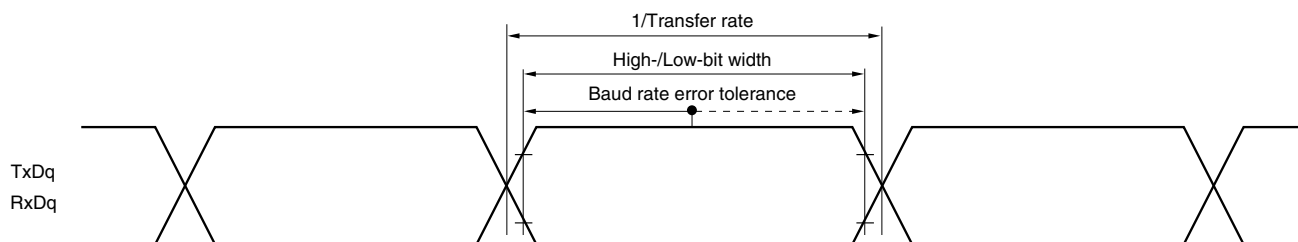
- Notes**
1. Transfer rate in the SNOOZE mode is 4800 bps only.
  2. The maximum operating frequencies of the CPU/peripheral hardware clock ( $f_{CLK}$ ) are:  
 HS (high-speed main) mode:  $24\text{ MHz}$  ( $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ )  
 $16\text{ MHz}$  ( $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ )

**Caution** Select the normal input buffer for the RxDq pin and the normal output mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

#### UART mode connection diagram (during communication at same potential)

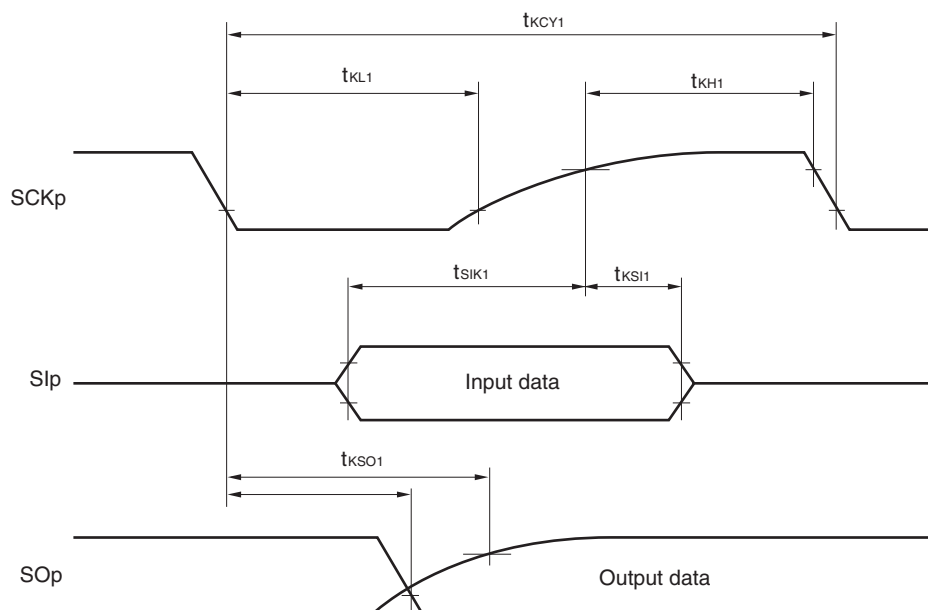


#### UART mode bit width (during communication at same potential) (reference)

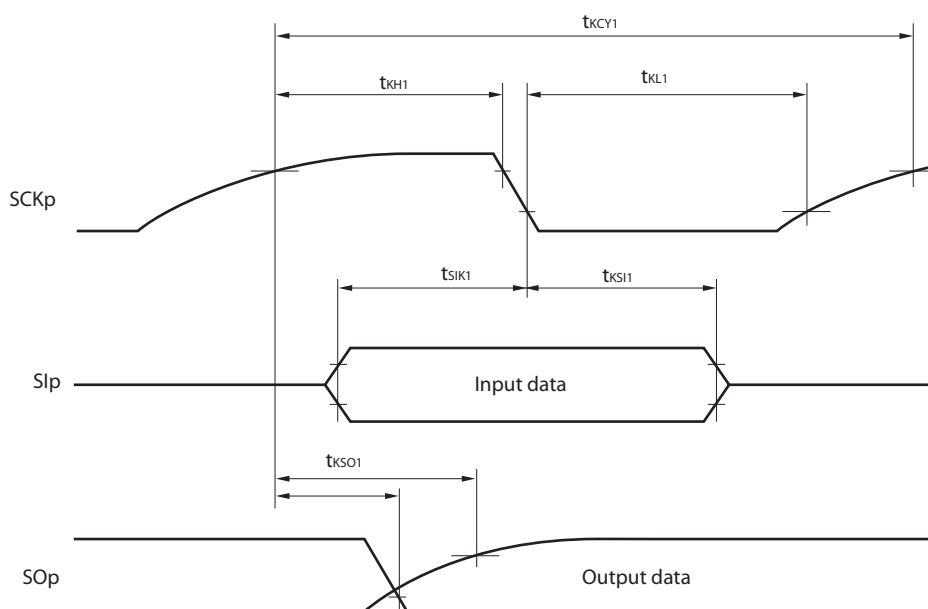


- Remarks**
1. q: UART number (q = 0 to 2), g: PIM, POM number (g = 0, 1)
  2.  $f_{MCK}$ : Serial array unit operation clock frequency  
 (Operation clock to be set by the serial clock select register m (SPSm) and the CKSmn bit of serial mode register mn (SMRmn).  
 m: Unit number, n: Channel number (mn = 00 to 03, 10, 11))

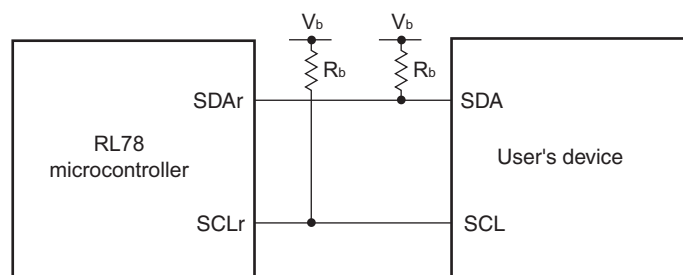
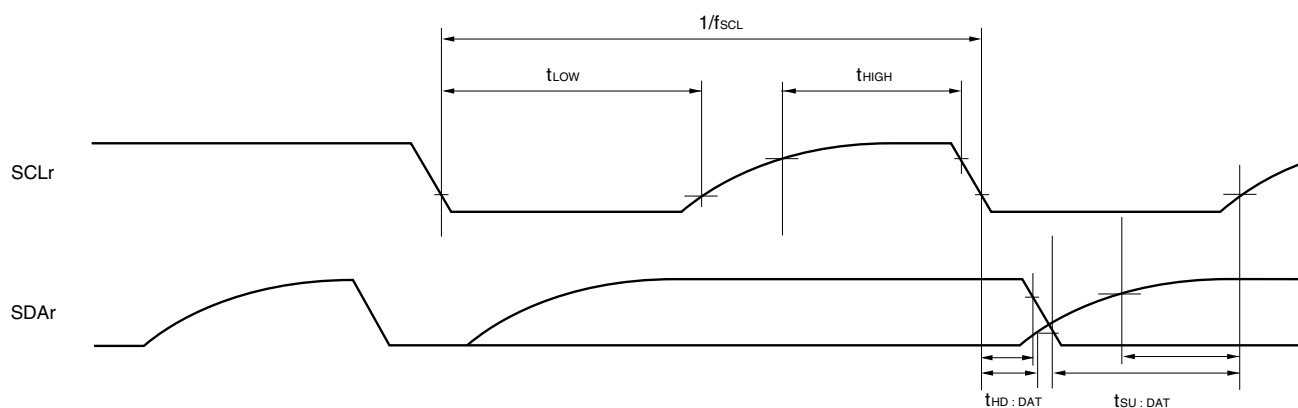
**CSI mode serial transfer timing (master mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1)**



**CSI mode serial transfer timing (master mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**



**Remark** p: CSI number (p = 00, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0)

**Simplified I<sup>2</sup>C mode connection diagram (during communication at different potential)****Simplified I<sup>2</sup>C mode serial transfer timing (during communication at different potential)**

- Remarks 1.**  $R_b$  [ $\Omega$ ]: Communication line (SDAr, SCLr) pull-up resistance,  $C_b$  [F]: Communication line (SDAr, SCLr) load capacitance,  $V_b$  [V]: Communication line voltage
- 2.**  $r$ : IIC Number ( $r = 00, 20$ )
- 3.**  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the serial clock select register  $m$  (SPS $m$ ) and the CKS $m$  $n$  bit of serial mode register  $m$  $n$  (SMR $m$  $n$ ).  
 $m$ : Unit number ( $m = 0, 1$ ),  $n$ : Channel number ( $n = 0$ ))

## 3.6.4 LVD circuit characteristics

**LVD Detection Voltage of Reset Mode and Interrupt Mode****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $V_{PDR} \leq V_{DD} \leq 5.5$  V,  $V_{SS} = 0$  V)**

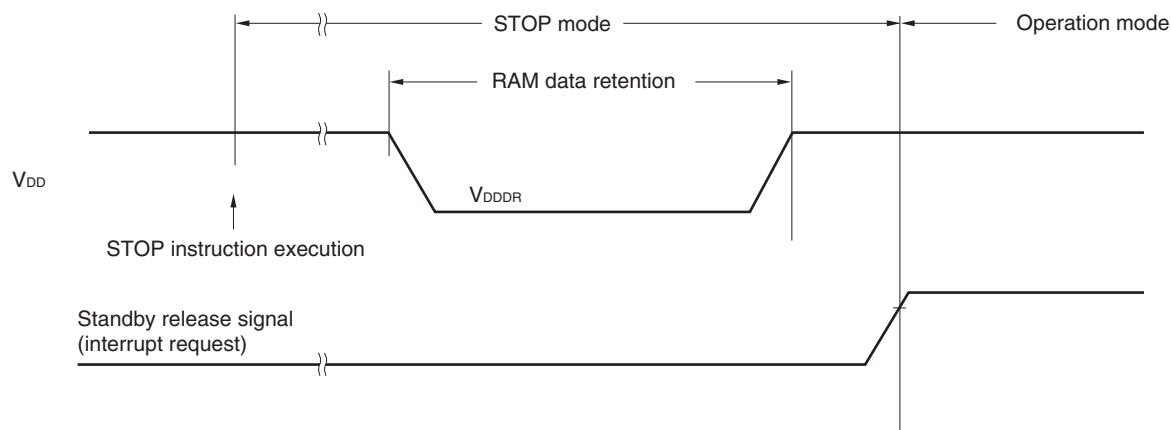
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Detection supply voltage	$V_{LVD0}$	Power supply rise time	3.90	4.06	4.22	V
		Power supply fall time	3.83	3.98	4.13	V
	$V_{LVD1}$	Power supply rise time	3.60	3.75	3.90	V
		Power supply fall time	3.53	3.67	3.81	V
	$V_{LVD2}$	Power supply rise time	3.01	3.13	3.25	V
		Power supply fall time	2.94	3.06	3.18	V
	$V_{LVD3}$	Power supply rise time	2.90	3.02	3.14	V
		Power supply fall time	2.85	2.96	3.07	V
	$V_{LVD4}$	Power supply rise time	2.81	2.92	3.03	V
		Power supply fall time	2.75	2.86	2.97	V
	$V_{LVD5}$	Power supply rise time	2.70	2.81	2.92	V
		Power supply fall time	2.64	2.75	2.86	V
	$V_{LVD6}$	Power supply rise time	2.61	2.71	2.81	V
		Power supply fall time	2.55	2.65	2.75	V
	$V_{LVD7}$	Power supply rise time	2.51	2.61	2.71	V
		Power supply fall time	2.45	2.55	2.65	V
Minimum pulse width	$t_{LW}$		300			$\mu\text{s}$
Detection delay time					300	$\mu\text{s}$

## &lt;R&gt; 3.7 RAM Data Retention Characteristics

**( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Data retention supply voltage	$V_{DDDR}$		1.44 <sup>Note</sup>		5.5	V

<R> Note This depends on the POR detection voltage. For a falling voltage, data in RAM are retained until the voltage reaches the level that triggers a POR reset but not once it reaches the level at which a POR reset is generated.



## 3.8 Flash Memory Programming Characteristics

**( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
System clock frequency	$f_{CLK}$		1		24	MHz
Code flash memory rewritable times <small>Notes 1, 2, 3</small>	$C_{erwr}$	Retained for 20 years $T_A = 85^\circ\text{C}$ <small>Notes 4</small>	1,000			Times
Data flash memory rewritable times <small>Notes 1, 2, 3</small>		Retained for 1 year $T_A = 25^\circ\text{C}$ <small>Notes 4</small>		1,000,000		
		Retained for 5 years $T_A = 85^\circ\text{C}$ <small>Notes 4</small>	100,000			
		Retained for 20 years $T_A = 85^\circ\text{C}$ <small>Notes 4</small>	10,000			

- Notes**
- 1 erase + 1 write after the erase is regarded as 1 rewrite. The retaining years are until next rewrite after the rewrite.
  2. When using flash memory programmer and Renesas Electronics self programming library
  3. These are the characteristics of the flash memory and the results obtained from reliability testing by Renesas Electronics Corporation.
  4. This temperature is the average value at which data are retained.